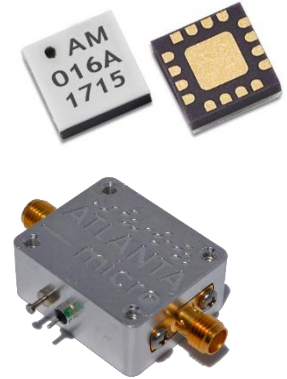


AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

Description

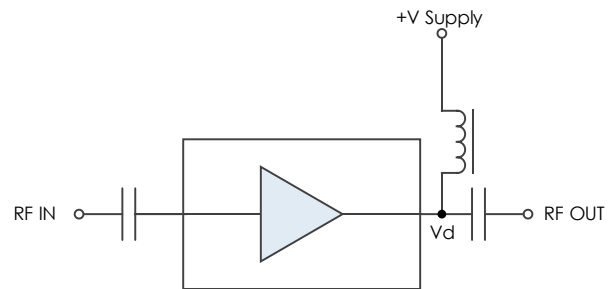
AM1016A is a high dynamic range cascadable gain block covering the 20 MHz to 6 GHz frequency range. It operates from a +3.3 VDC supply and exhibits a flat frequency response and high third order intercept performance while also providing excellent gain stability over the operating temperature range. With internal 50Ω matching and packaged in a 3mm QFN, the AM1016A represents a compact total PCB footprint.



Features

- 15 dB Gain
- 2.5 dB Noise Figure
- +30 dBm OIP3
- +18 dBm P1dB
- +19 dBm PSat
- +3.3V, 55 mA
- 3mm QFN Package
- -40C to +85C Operation
- Unconditionally Stable

Functional Diagram



Characteristic Performance

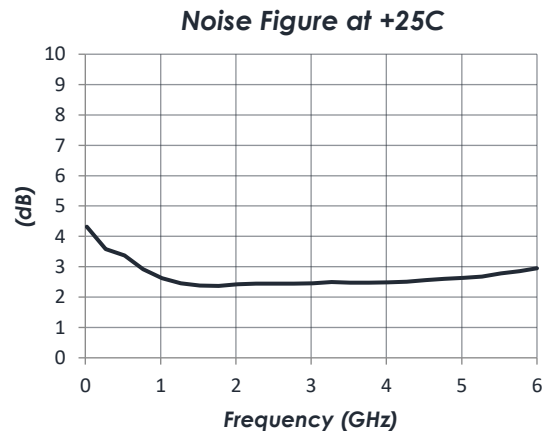
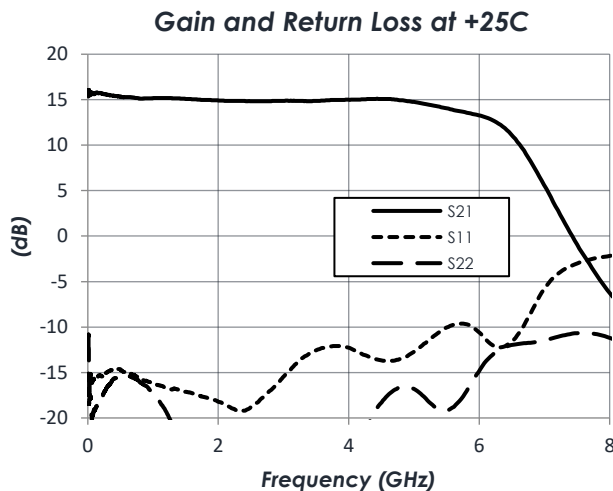


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Revision History

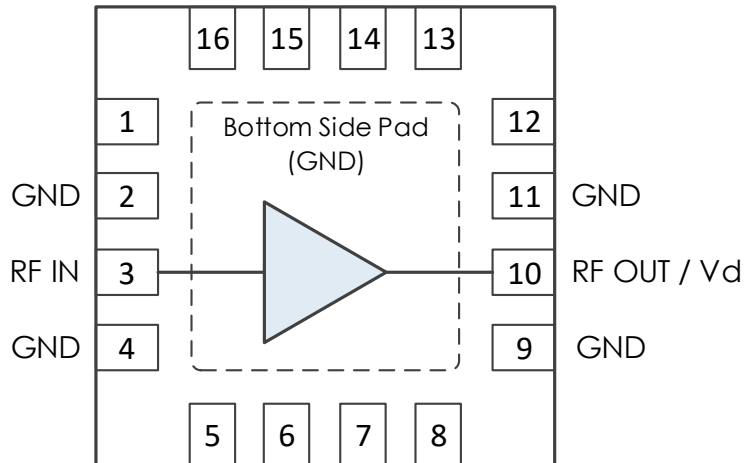
Date	Revision Number	Notes
December 13, 2017	A	Initial Release
December 17, 2017	A1	Formatting Changes
August 2, 2019	2	Updated to Latest Datasheet Format. Min/Typ/Max Current Values Changed. RF-Shielded Module Information Added.

AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

Pin Layout and Definitions

NOTE: All Non-Named Pins Are NC or GND



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground – Common
3	RF IN	RF Input – 50 ohms – DC Coupled, External DC Block Required
4	GND	Ground - Common
5 - 8	NC	Not Connected*
9	GND	Ground – Common
10	RF OUT / Vd	RF Output and DC Power Input – 50 ohms – DC Coupled, External DC Block Required
11	GND	Ground - Common
12 - 16	NC	Not Connected*
Bottom Pad	GND	Ground – Common

*Note: NC pins may be grounded or left open.

AM1016A – Amplifier

20 MHz to 6 GHz Gain Block



Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Device Voltage, Vd	0.0 V	+4.0 V
RF Input Power		+15 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.
Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage, Vsupply	+3.0 V	+3.3 V	+3.8 V
Device Voltage, Vd	+2.7V	+3.0 V	+3.5 V
Operating Case Temperature	-40 C	+25 C	+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ_{JC})	137

AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Device Voltage, Vd		+2.7 V	+3.0 V	+3.5 V
DC Supply Current	Vsupply = +3.3 V	50 mA	55 mA	70 mA
Power Dissipated	Vsupply = +3.3 V	0.17 W	0.18 W	0.23 W

RF Performance

(T = 25 °C unless otherwise specified)

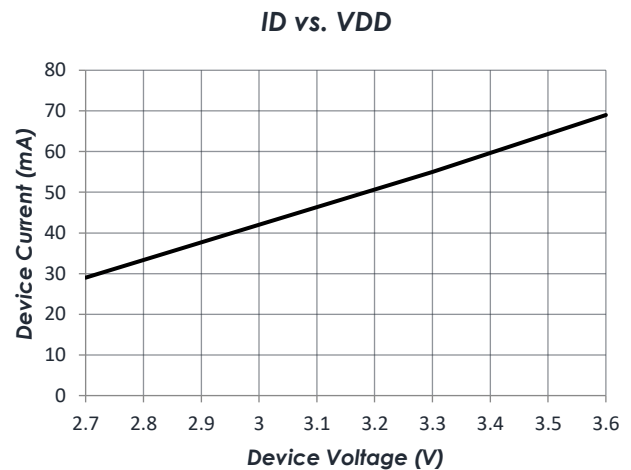
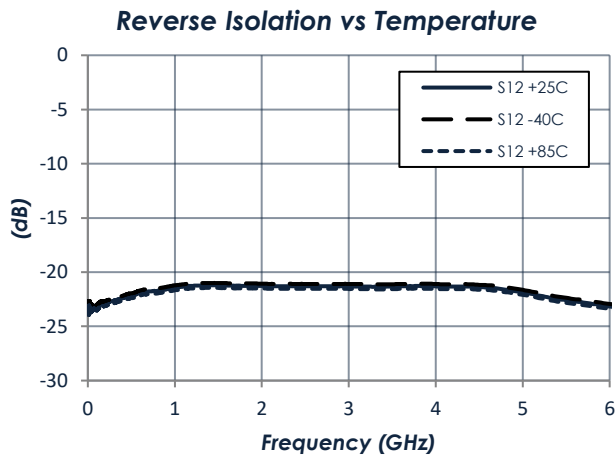
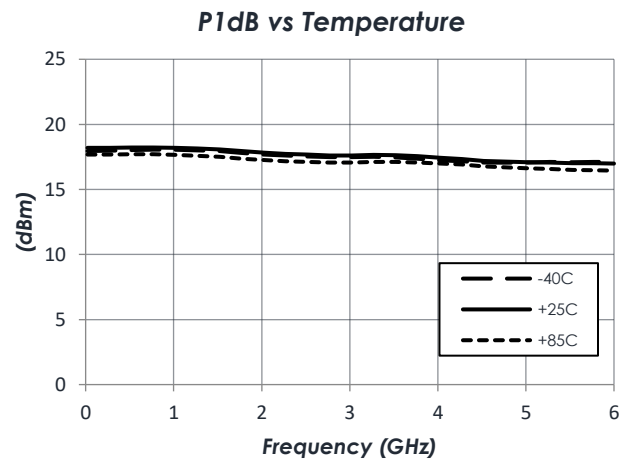
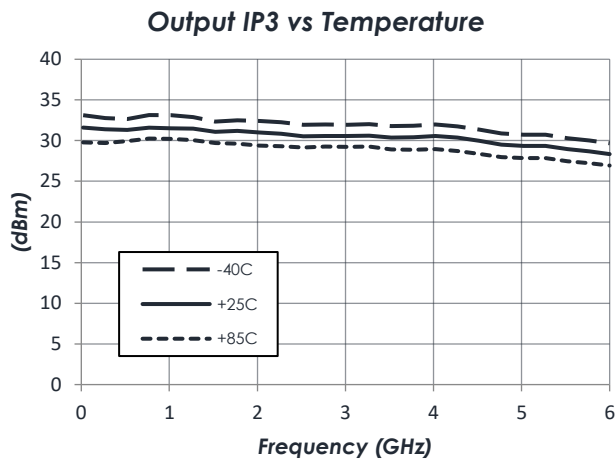
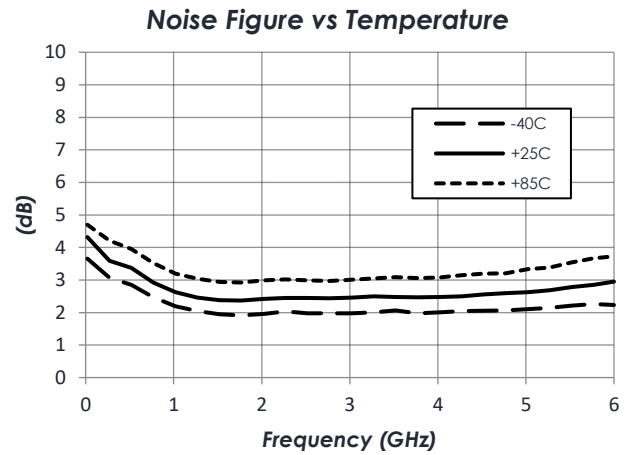
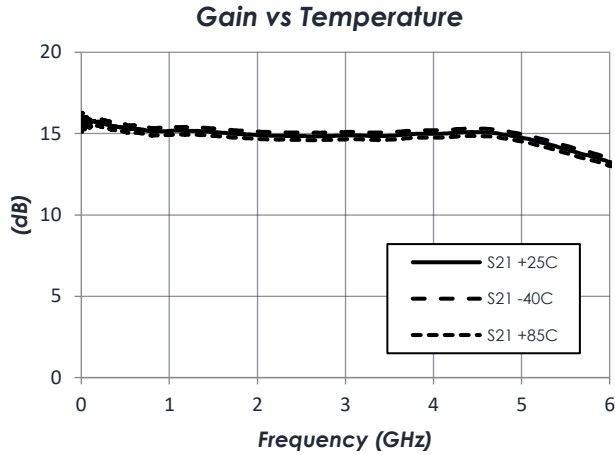
Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		20 MHz		6 GHz
Gain	f = 3 GHz		15 dB	
Output IP3	f = 3 GHz		+30 dB	
Output P1dB	f = 3 GHz		+17 dB	
Noise Figure	f = 3 GHz		2.5 dB	

AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

Typical Performance

(Vd = +3.0V, ID=55mA)



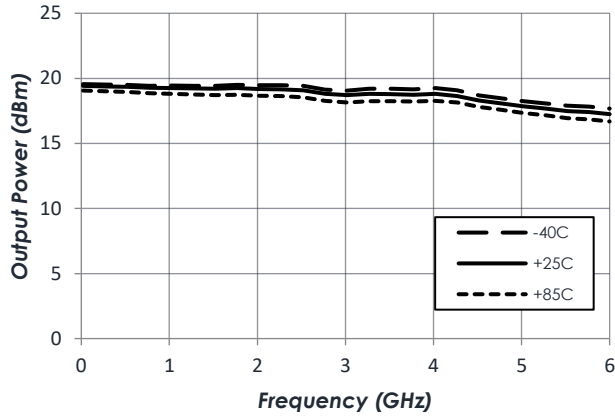
AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

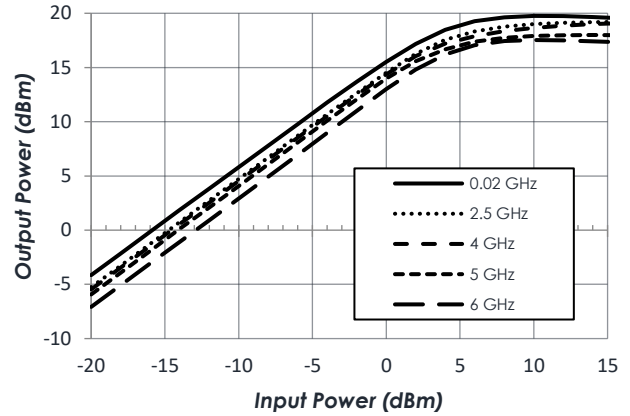
Typical Performance (continued)

(Vd = +3.0V, ID=55mA)

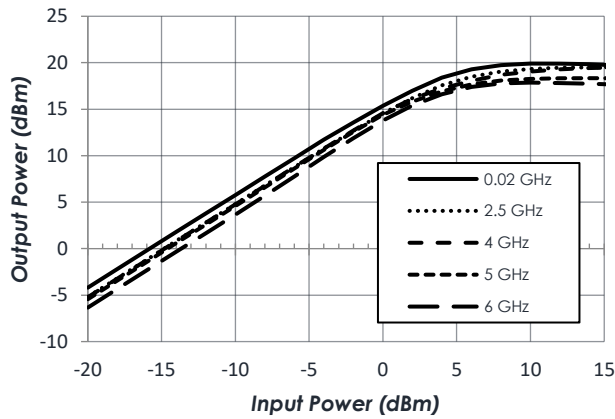
P_{Sat} vs Temperature



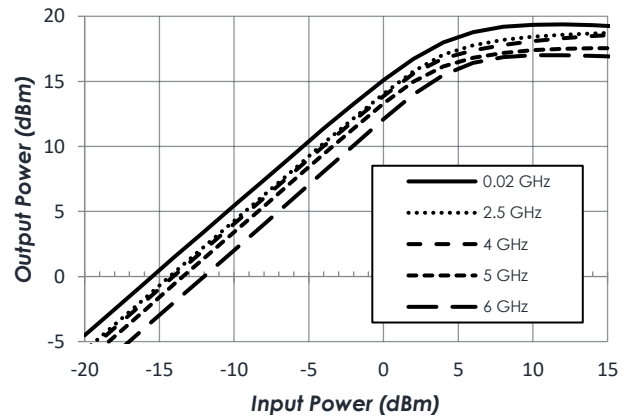
Pin vs. Pout at +25C



Pin vs. Pout at -40C



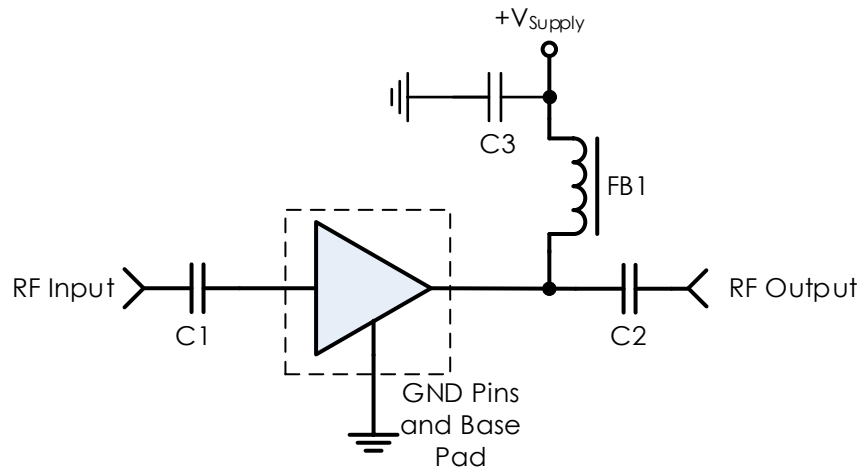
Pin vs. Pout at +85C



AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 μ F	0402BB104KW160	Passives Plus
C3	0.1 μ F	GRM155R71C104KA88	Murata
FB1	-	MMZ1005A222E	TDK

Notes:

1. NC pins may be grounded or left open.
2. DC blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance.

AM1016A – Amplifier

20 MHz to 6 GHz Gain Block



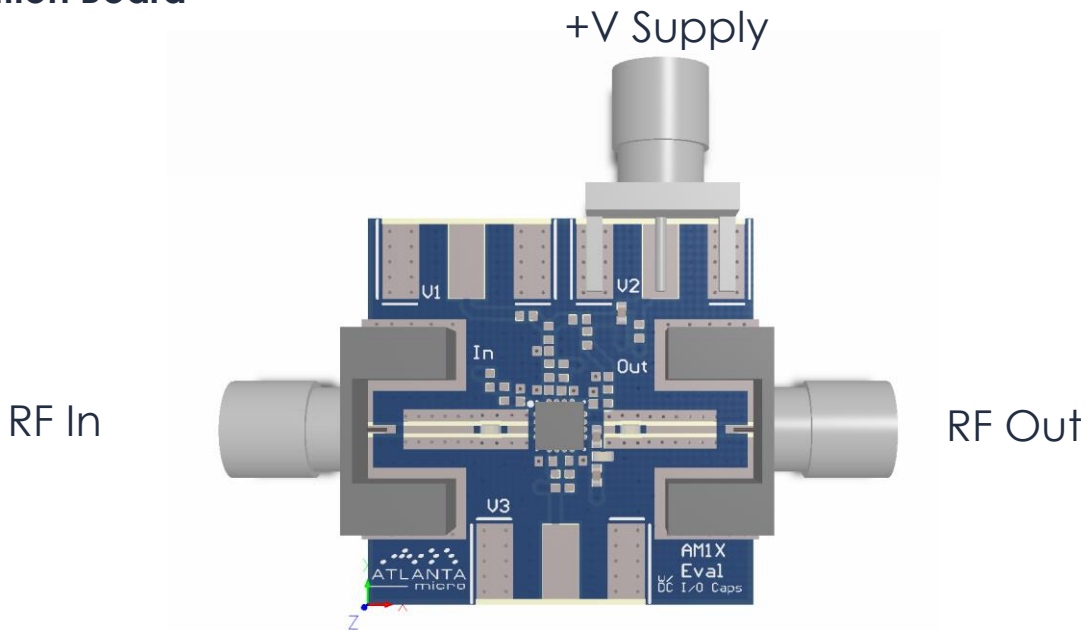
Part Ordering Details

Description	Part Number
3mm 16 Lead QFN	AM1016A
AM1016A Evaluation Board	AM1016A Eval
AM1016A in 0.95" x 1.13" x 0.6" RF-Shielded Module with Integrated Bias Tee and Field Replaceable SMA Connectors	AM1016A-M

Related Parts

Part Number	Description
AM1016B	20 MHz to 6 GHz +3.3V Gain Block
AM1018A	20 MHz to 6 GHz +3.3V Gain Block
AM1018B	20 MHz to 6 GHz +5.0V Gain Block
AM1018C	20 MHz to 6 GHz +5.0V Gain Block
AM1025B	20 MHz to 3 GHz +8.0V Gain Block (High P1dB)
AM1031C	20 MHz to 8 GHz +3.3V Gain Block
AM1063-1	DC to 10 GHz Gain Block
AM1064-1	DC to 8 GHz Gain Block
AM1085	DC to 6 GHz +5.0V Gain Block
AM1090	DC to 6 GHz +5.0V or +8.0V Gain Block

Evaluation Board



To obtain price, delivery, or to place an order contact sales@atlantamicro.com
Atlanta Micro Inc., 3720 Davinci Ct, Suite 125, Norcross, GA 30092 • Phone: (470) 253-7640 • www.atlantamicro.com

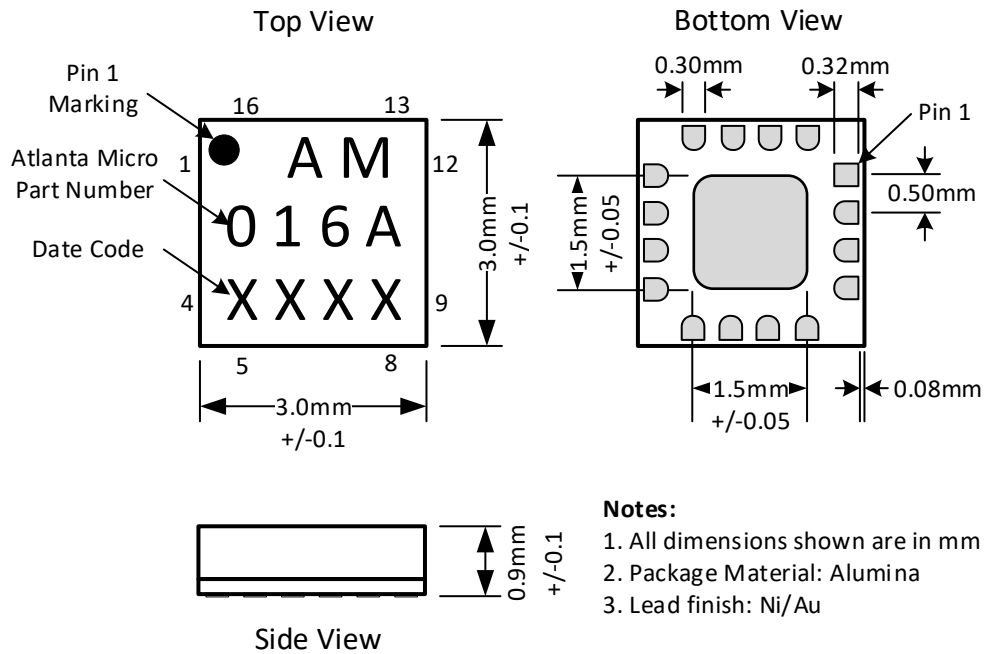
AM1016A – Amplifier

20 MHz to 6 GHz Gain Block

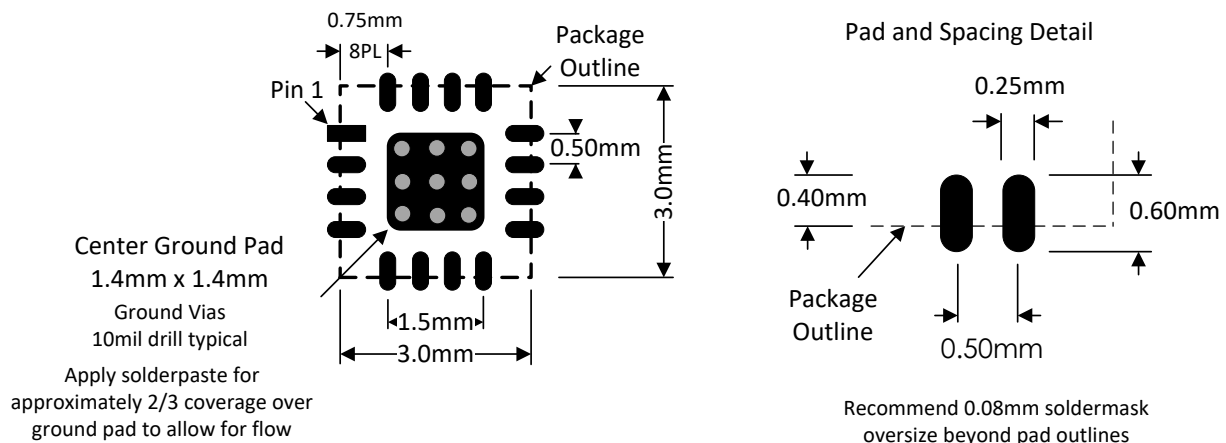


3mm 16 Lead QFN Details

Package Drawing



Recommended Footprint



AM1016A – Amplifier

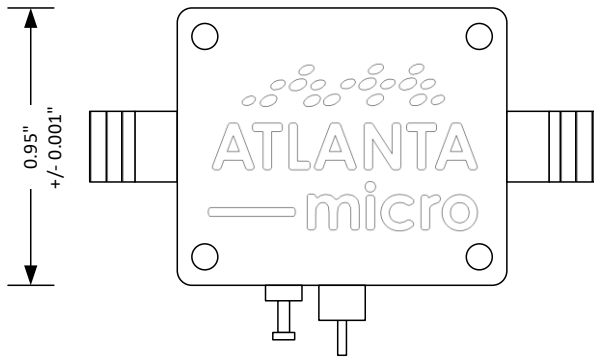
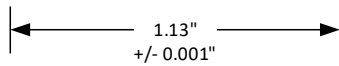
20 MHz to 6 GHz Gain Block



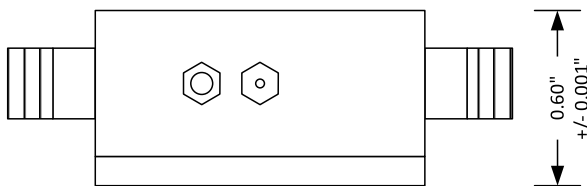
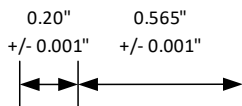
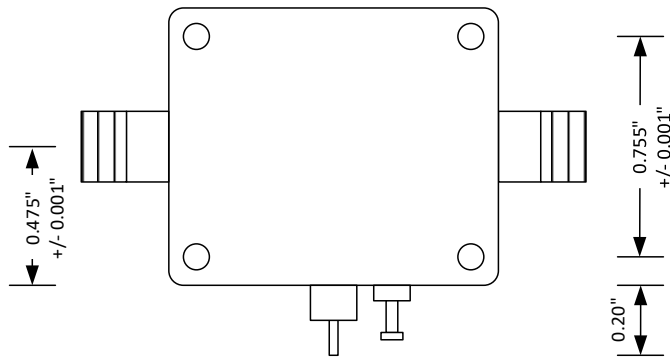
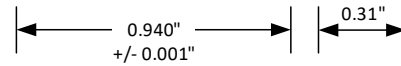
RF Shielded Module Details



Top View



Bottom View



Front View

Notes:

- 1. All dimensions shown are in inches
- 2. Module material: Aluminum
- 3. Mounting Holes: 4-40 threaded on top side
- 4. RF I/O Interface: SMA
- 5. Power via metal turrets

Component Compliance Information

RoHS: Atlanta Micro, Inc. hereby certifies that all products comply with the EC Directive 2011/65/EC on the Restriction of Hazardous Substances, commonly known as EU-RoHS 6 and 10. All products supplied by Atlanta Micro shall be compliant with the European Directive 2011/65/EC based on the following substance list.

Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylhexyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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